BC337, BC337-25, BC337-40

Amplifier Transistors

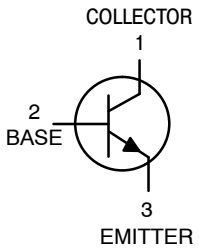
NPN Silicon

ON Semiconductor®

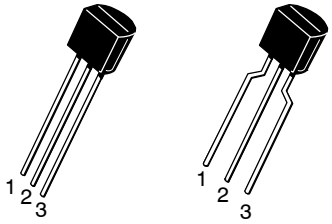
http://onsemi.com

Features

- These are Pb−Free Devices



TO−92
CASE 29
STYLE 17



STRAIGHT LEAD
BULK PACK

BENT LEAD
TAPE & REEL
AMMO PACK

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector − Emitter Voltage	V_{CEO}	45	Vdc
Collector − Base Voltage	V_{CBO}	50	Vdc
Emitter − Base Voltage	V_{EBO}	5.0	Vdc
Collector Current − Continuous	I_C	800	mAdc
Total Device Dissipation @ T_A = 25°C Derate above 25°C	P_D	625 5.0	mW mW/°C
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	−55 to +150	°C

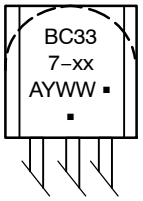
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction−to−Case	$R_{\theta JC}$	83.3	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MARKING DIAGRAM



BC337−xx = Device Code
(Refer to page 4)
A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb−Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector−Emitter Breakdown Voltage (I_C = 10 mA, I_B = 0)		$V_{(BR)CEO}$	45	−	−	Vdc
Collector−Emitter Breakdown Voltage (I_C = 100 μA, I_E = 0)		$V_{(BR)CES}$	50	−	−	Vdc
Emitter−Base Breakdown Voltage (I_E = 10 μA, I_C = 0)		$V_{(BR)EBO}$	5.0	−	−	Vdc
Collector Cutoff Current (V_{CB} = 30 V, I_E = 0)		I_{CBO}	−	−	100	nAdc
Collector Cutoff Current (V_{CE} = 45 V, V_{BE} = 0)		I_{CES}	−	−	100	nAdc
Emitter Cutoff Current (V_{EB} = 4.0 V, I_C = 0)		I_{EBO}	−	−	100	nAdc
ON CHARACTERISTICS						
DC Current Gain		h_{FE}				−
(I_C = 100 mA, V_{CE} = 1.0 V)	BC337		100	−	630	
	BC337−25		160	−	400	
	BC337−40		250	−	630	
(I_C = 300 mA, V_{CE} = 1.0 V)			60	−	−	
Base−Emitter On Voltage (I_C = 300 mA, V_{CE} = 1.0 V)		$V_{BE(on)}$	−	−	1.2	Vdc
Collector−Emitter Saturation Voltage (I_C = 500 mA, I_B = 50 mA)		$V_{CE(sat)}$	−	−	0.7	Vdc
SMALL−SIGNAL CHARACTERISTICS						
Output Capacitance (V_{CB} = 10 V, I_E = 0, f = 1.0 MHz)		C_{ob}	−	15	−	pF
Current−Gain − Bandwidth Product (I_C = 10 mA, V_{CE} = 5.0 V, f = 100 MHz)		f_T	−	210	−	MHz

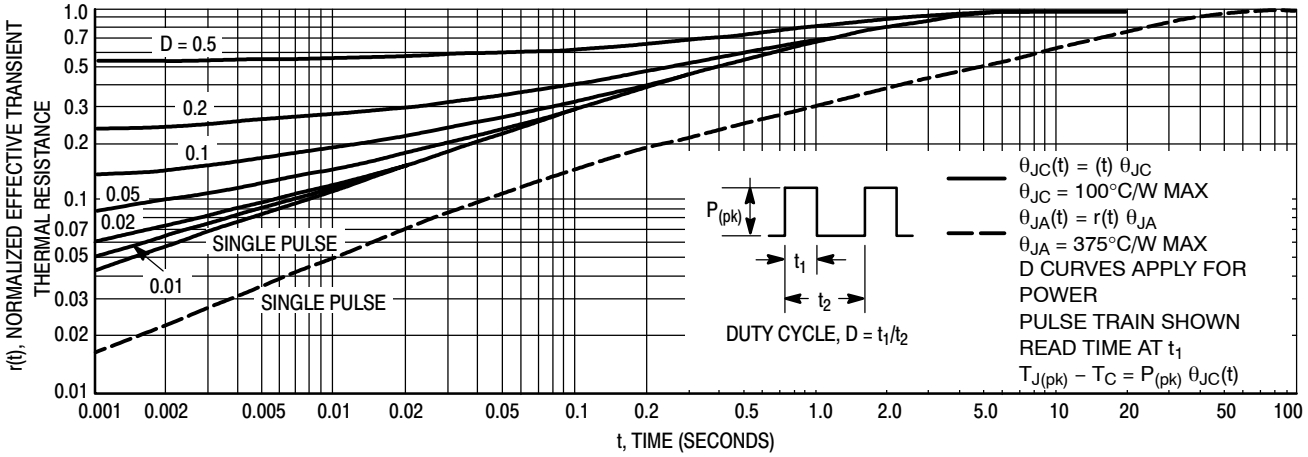


Figure 1. Thermal Response

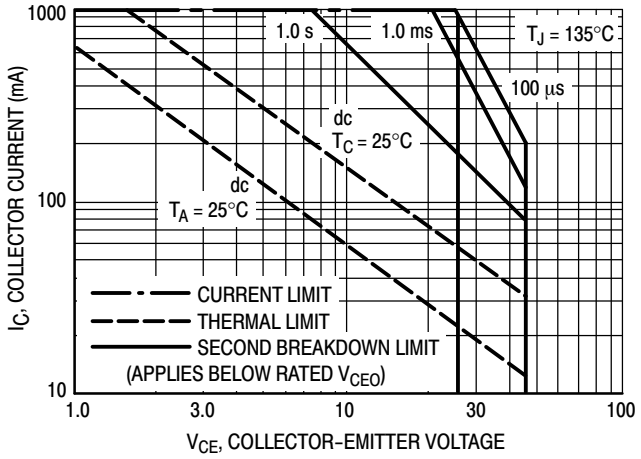


Figure 2. Active Region − Safe Operating Area

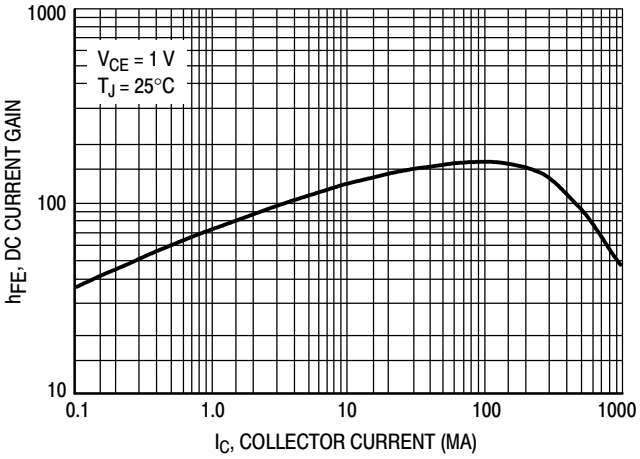


Figure 3. DC Current Gain

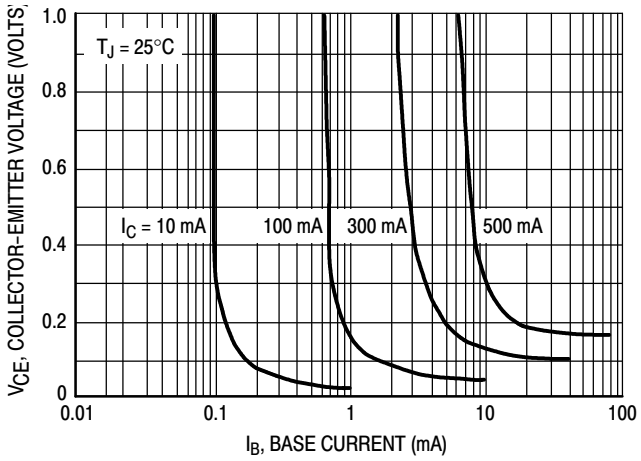


Figure 4. Saturation Region

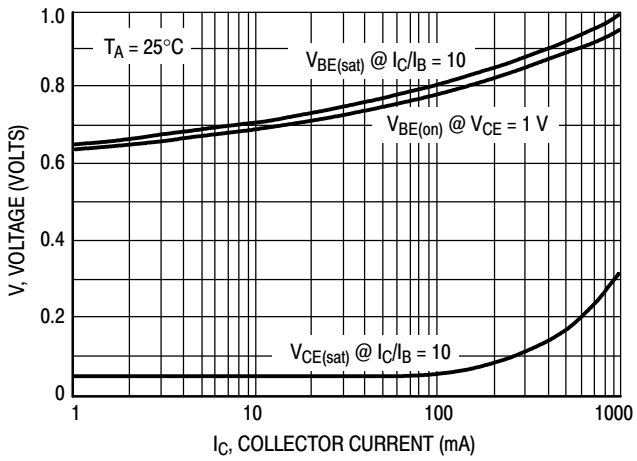


Figure 5. “On” Voltages

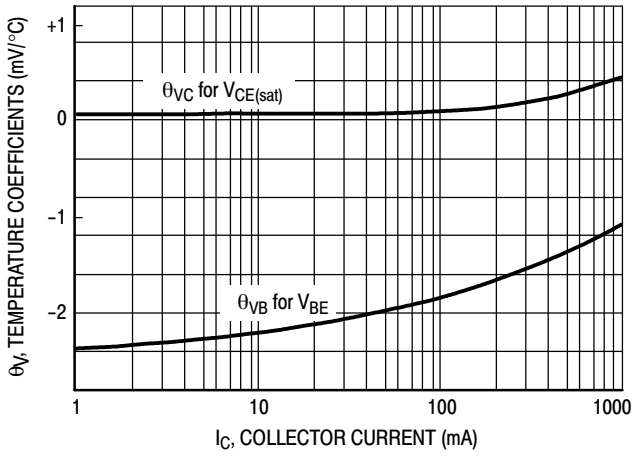


Figure 6. Temperature Coefficients

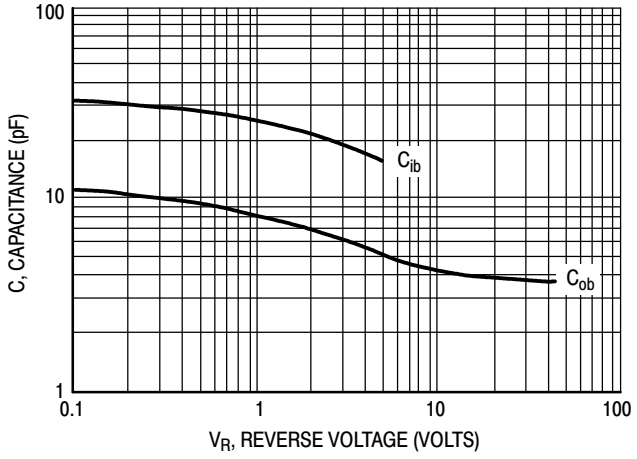


Figure 7. Capacitances

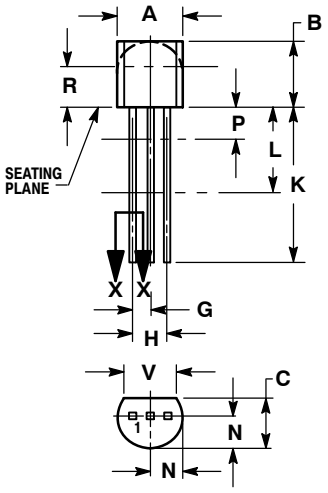
ORDERING INFORMATION

Device	Marking	Package	Shipping†
BC337G	7	TO−92 (Pb−Free)	5000 Units / Bulk
BC337RL1G	7		2000 / Tape & Reel
BC337−025G	7−25		5000 Units / Bulk
BC337−25RL1G	7−25		2000 / Tape & Reel
BC337−25ZL1G	7−25		2000 / Ammo Box
BC337−040G	7−40		5000 Units / Bulk
BC337−40RL1G	7−40		2000 / Tape & Reel
BC337−40ZL1G	7−40		2000 / Ammo Box

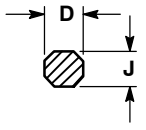
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO−92 (TO−226)
CASE 29−11
ISSUE AM



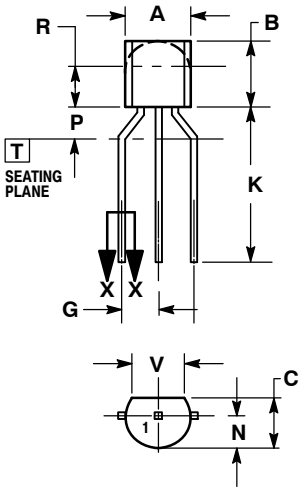
STRAIGHT LEAD
BULK PACK



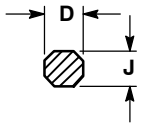
SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---



BENT LEAD
TAPE & REEL
AMMO PACK



SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS	
DIM	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---

STYLE 17:
PIN 1. COLLECTOR
2. BASE
3. EMITTER

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800−282−9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81−3−5773−3850

ON Semiconductor Website: **www.onsemi.com**

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative